

Typical Characteristics

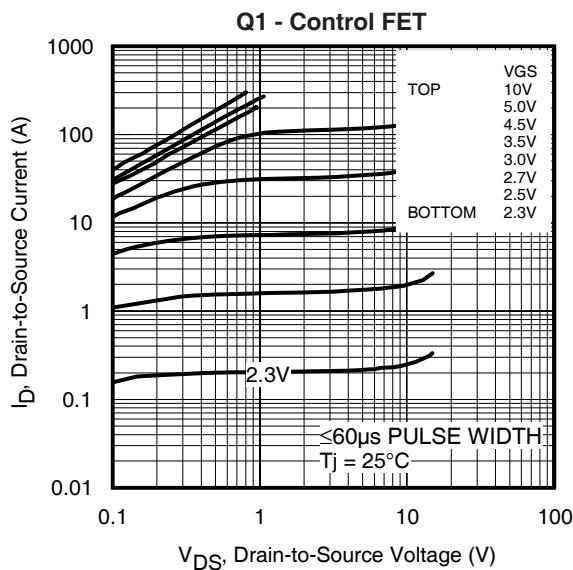


Fig 1. Typical Output Characteristics

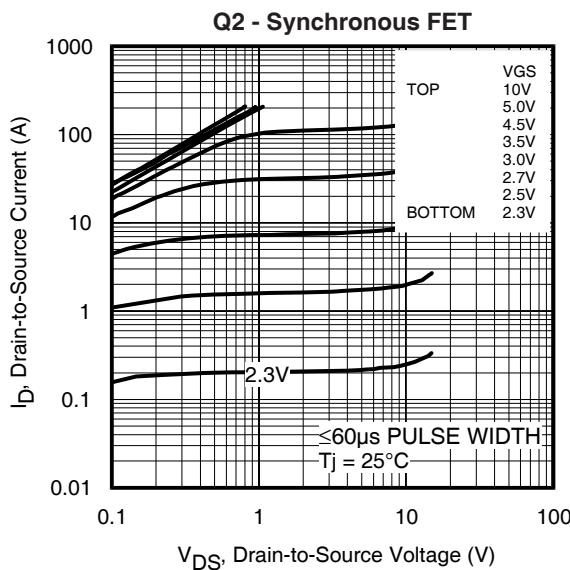


Fig 2. Typical Output Characteristics

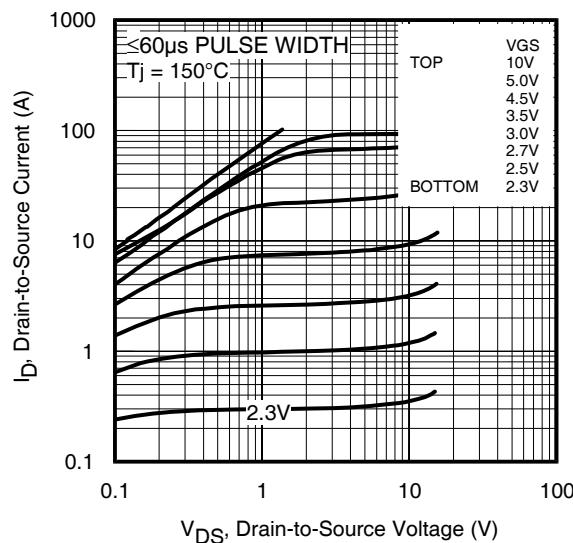


Fig 3. Typical Output Characteristics

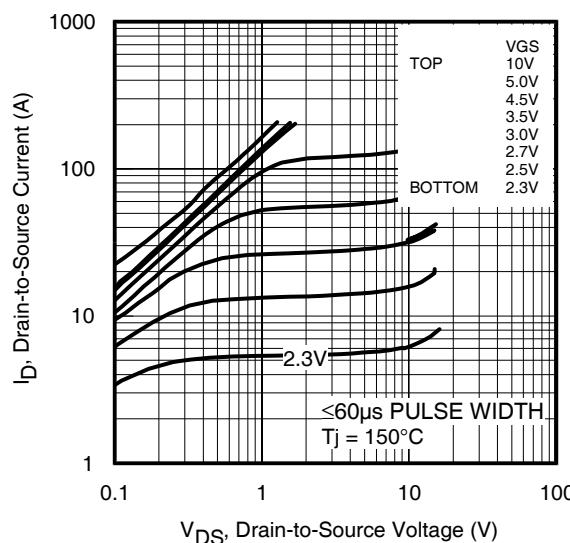


Fig 4. Typical Output Characteristics

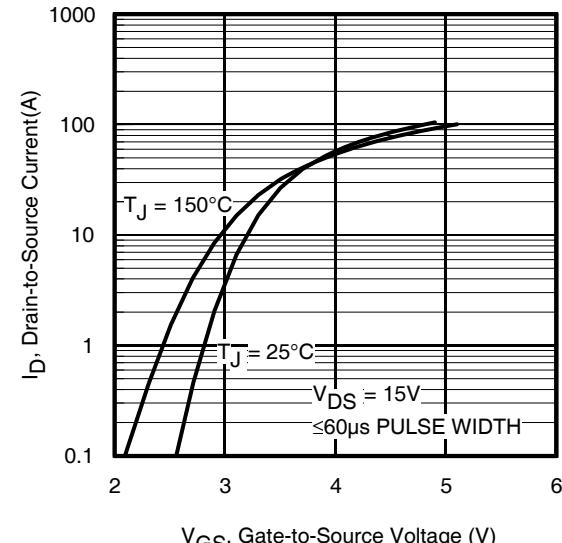
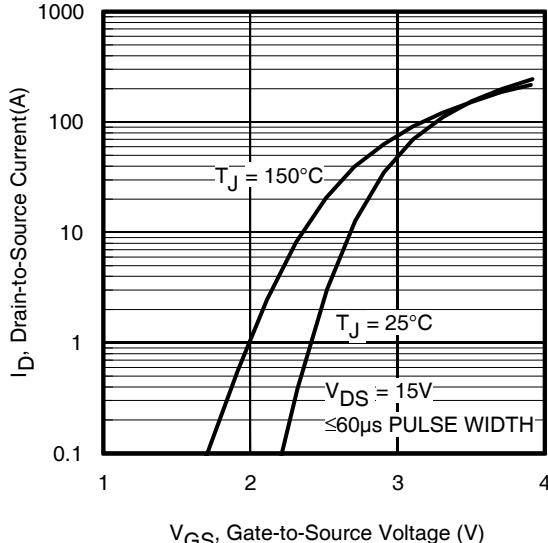


Fig 5. Typical Transfer Characteristics



IRFH7911PbF

Typical Characteristics

International
IR Rectifier

Q1 - Control FET

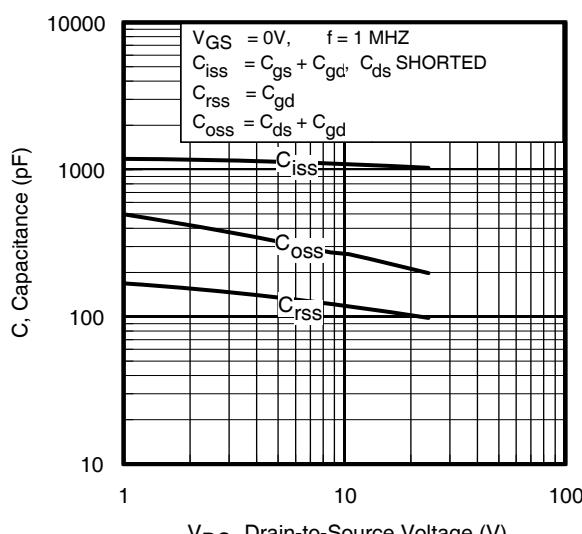


Fig 7. Typical Capacitance vs. Drain-to-Source Voltage

Q2 - Synchronous FET

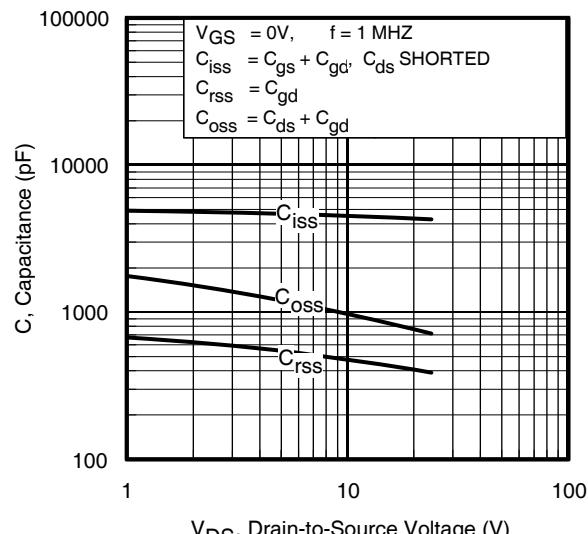


Fig 8. Typical Capacitance vs. Drain-to-Source Voltage

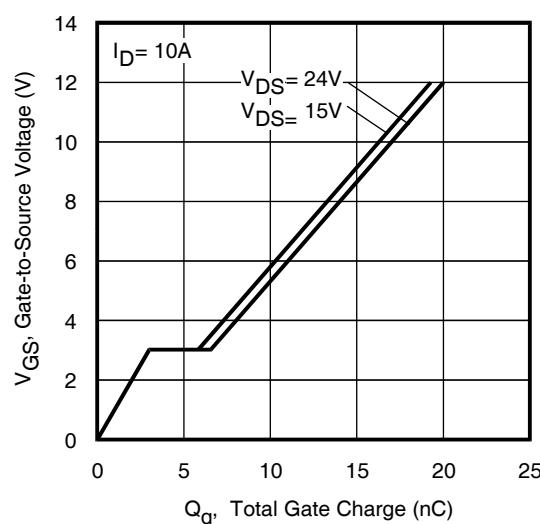


Fig 9. Typical Gate Charge vs. Gate-to-Source Voltage

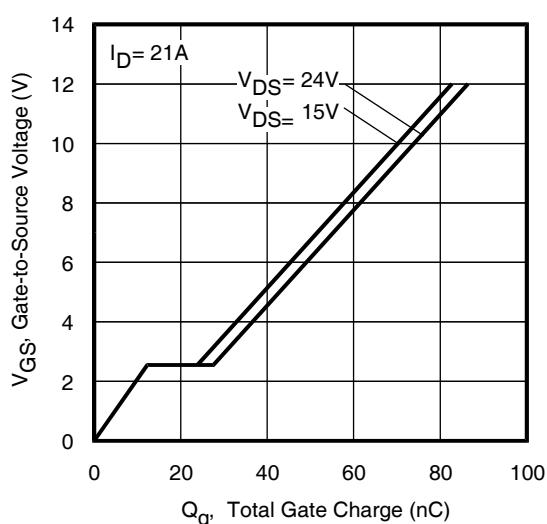


Fig 10. Typical Gate Charge vs. Gate-to-Source Voltage

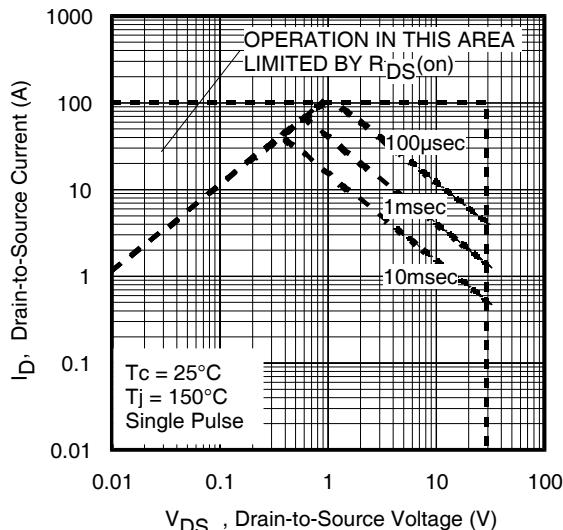


Fig 11. Maximum Safe Operating Area

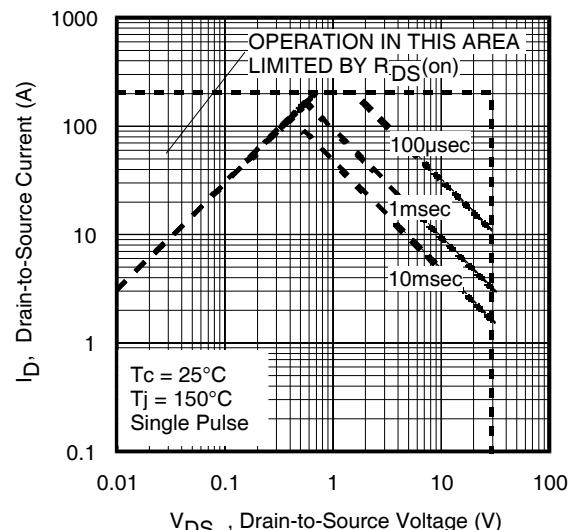


Fig 12. Maximum Safe Operating Area

Q1 - Control FET

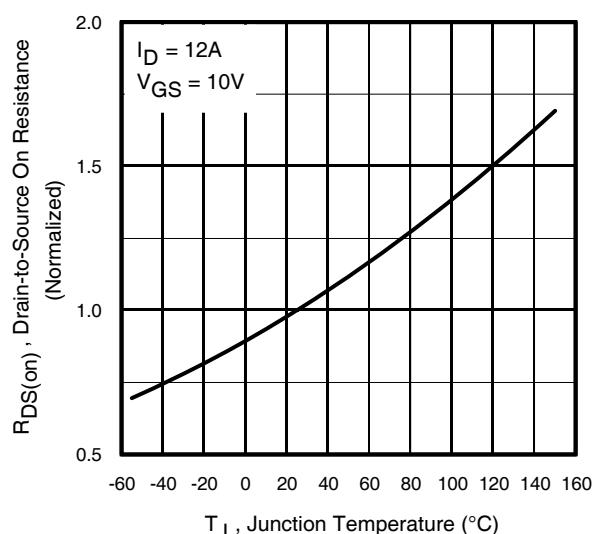


Fig 13. Normalized On-Resistance vs. Temperature

Q2 - Synchronous FET

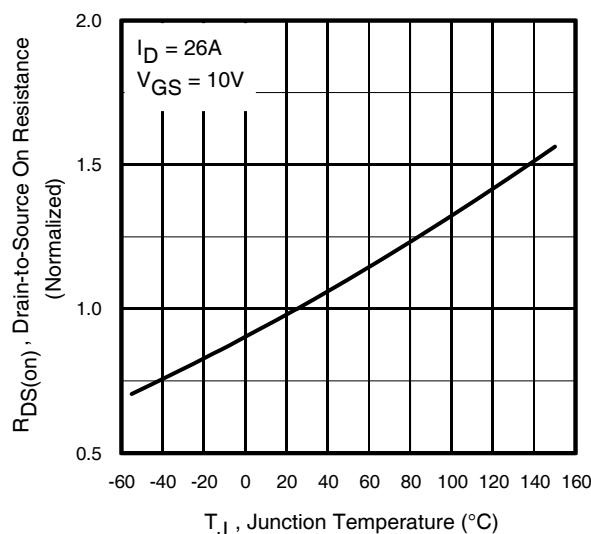


Fig 14. Normalized On-Resistance vs. Temperature

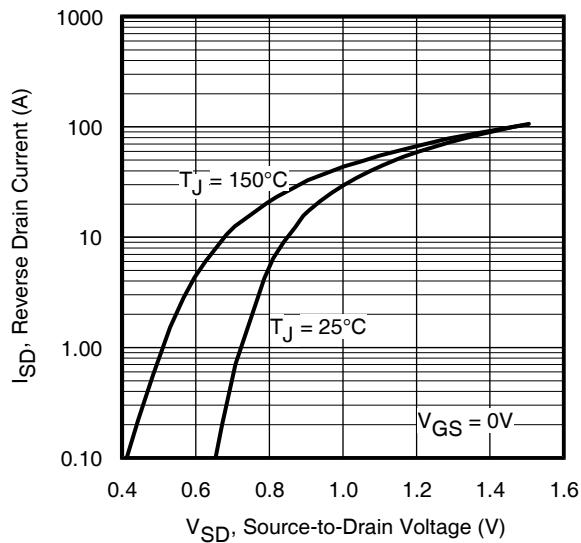


Fig 15. Typical Source-Drain Diode Forward Voltage

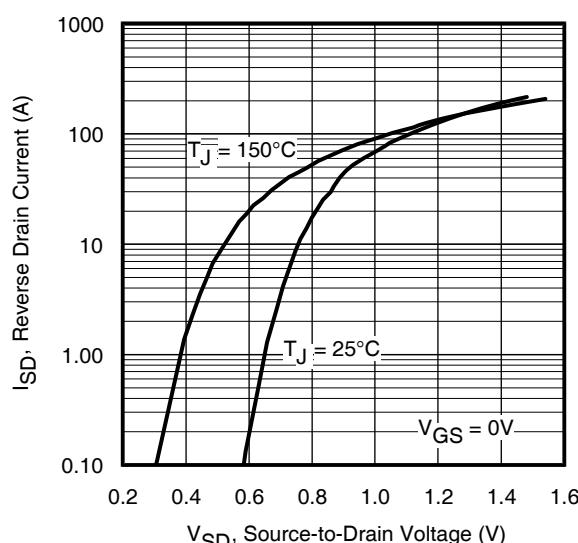


Fig 16. Typical Source-Drain Diode Forward Voltage

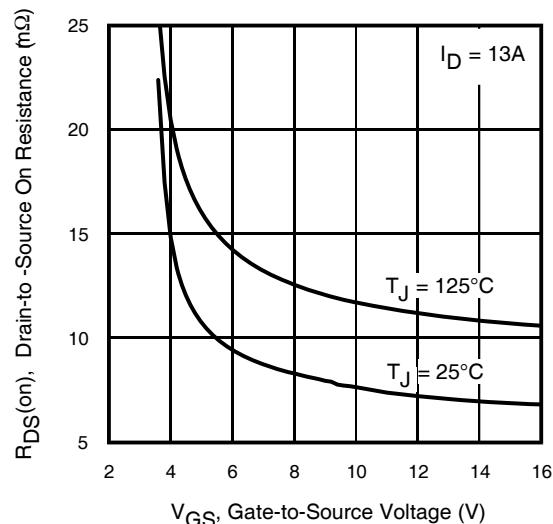


Fig 17. Typical On-Resistance vs. Gate Voltage

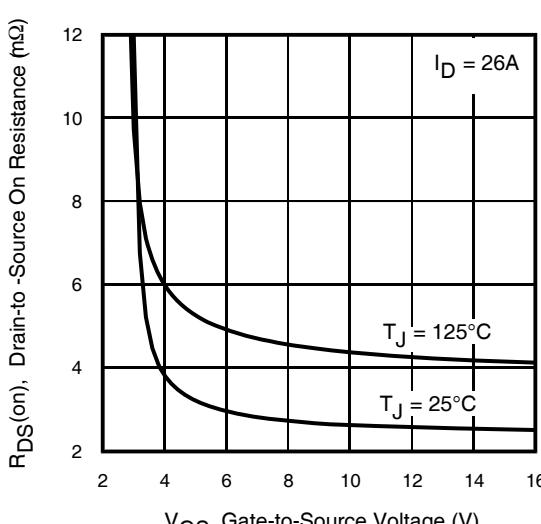


Fig 18. Typical On-Resistance vs. Gate Voltage

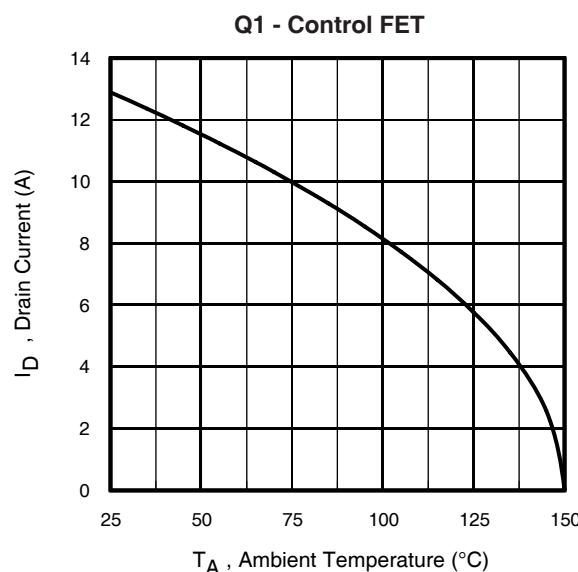


Fig 19. Maximum Drain Current vs. Ambient Temp.

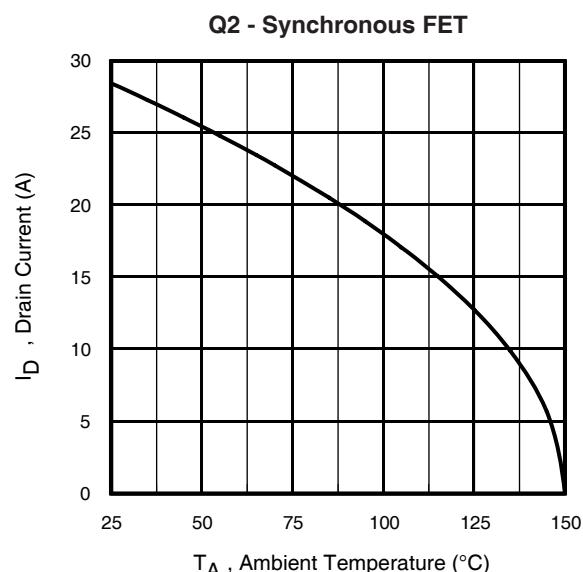


Fig 20. Maximum Drain Current vs. Ambient Temp.

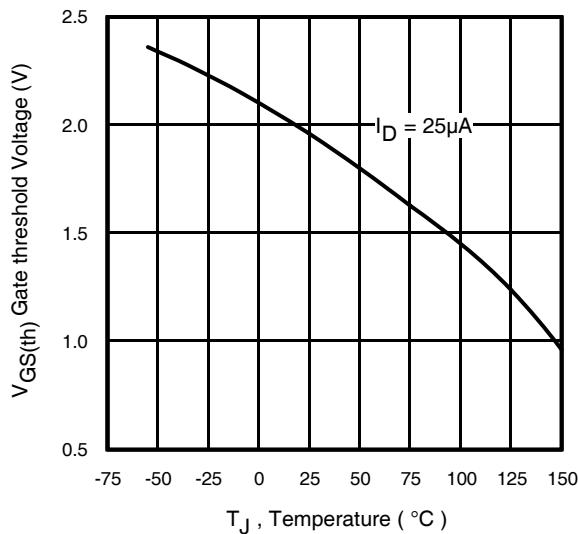


Fig 21. Threshold Voltage vs. Temperature

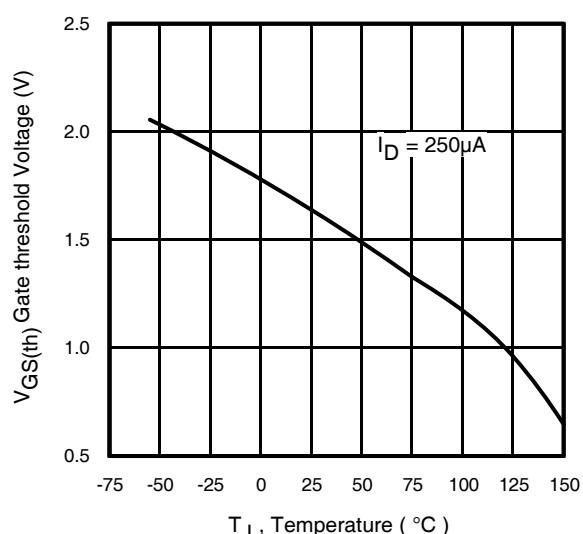


Fig 22. Threshold Voltage vs. Temperature

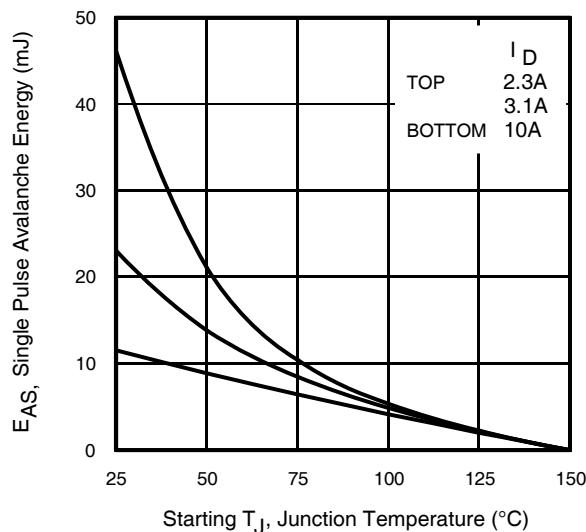


Fig 23. Maximum Avalanche Energy vs. Drain Current

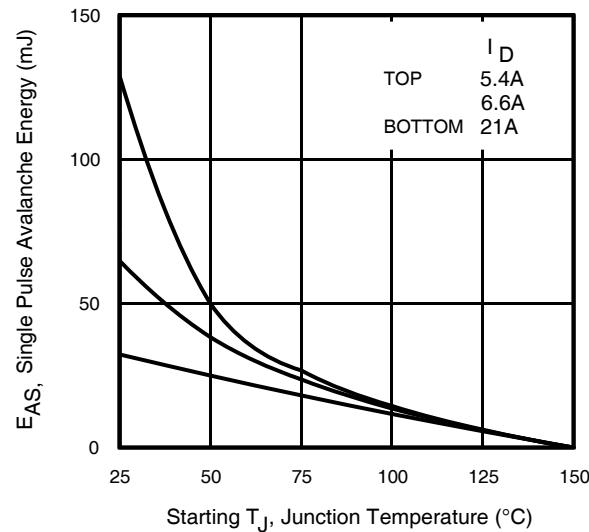


Fig 24. Maximum Avalanche Energy vs. Drain Current

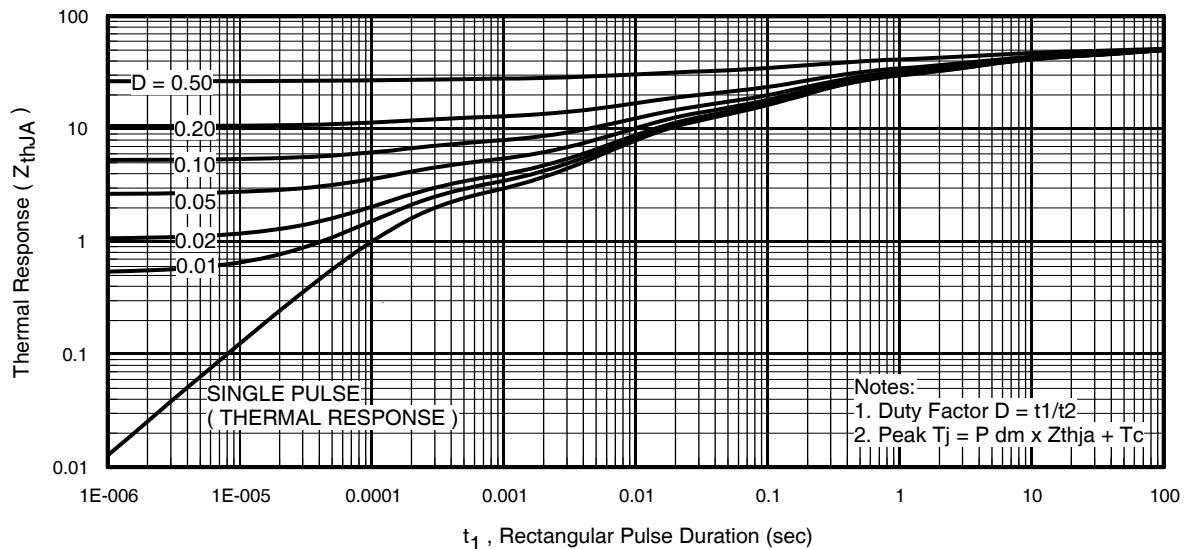


Fig 25. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient (Q1)

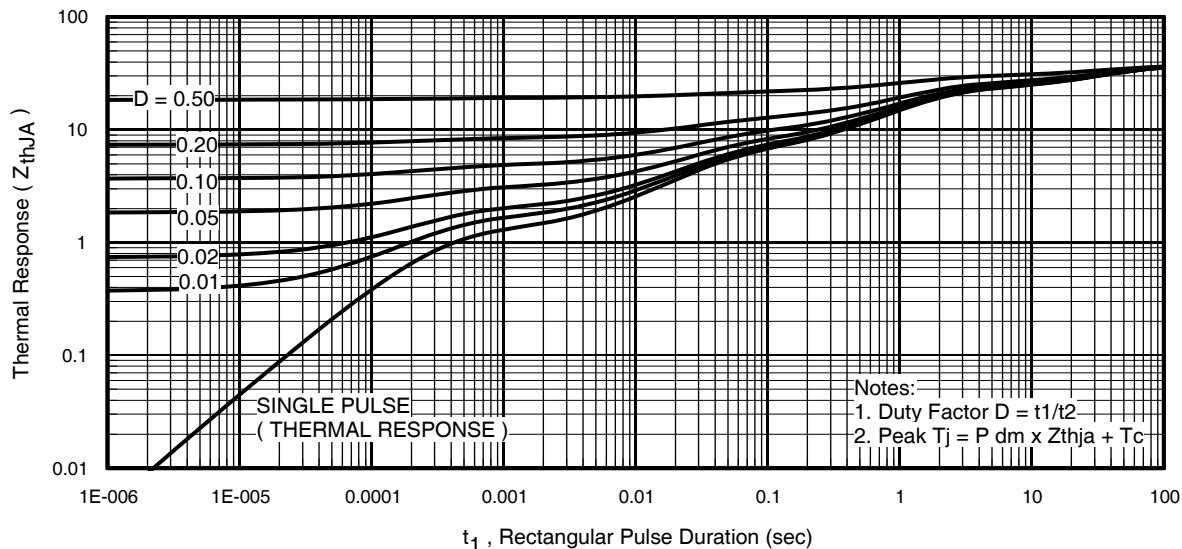


Fig 26. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient (Q2)

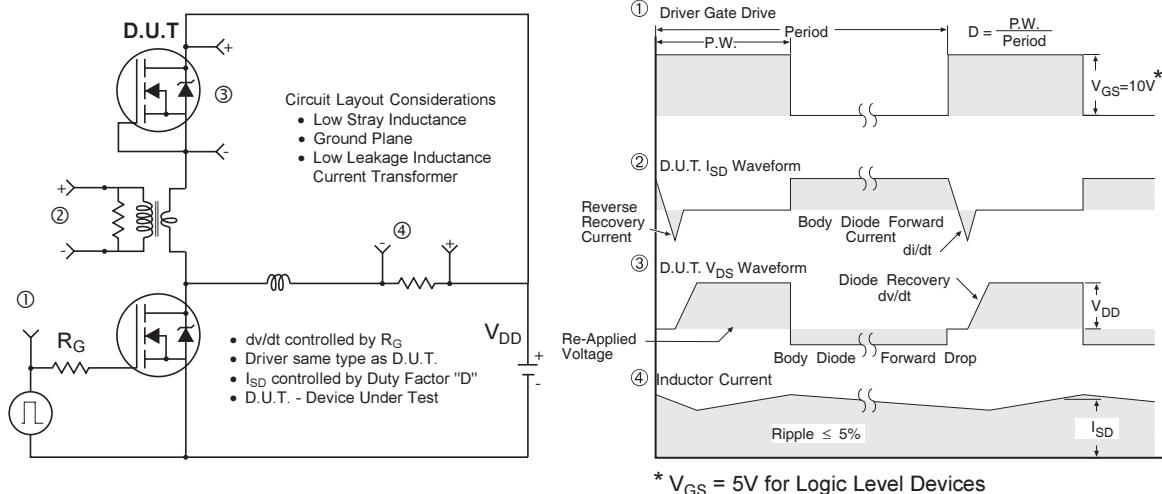


Fig 28. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

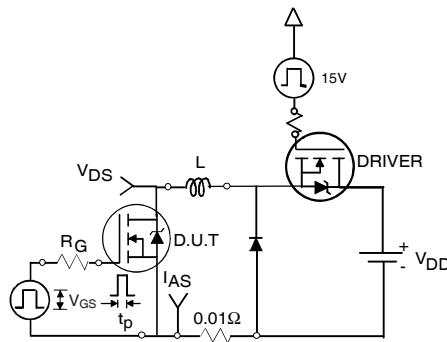


Fig 29a. Unclamped Inductive Test Circuit

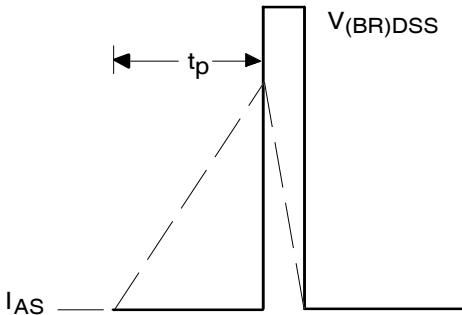


Fig 29b. Unclamped Inductive Waveforms

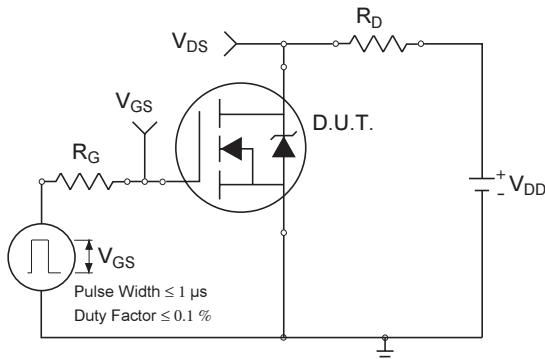


Fig 30a. Switching Time Test Circuit

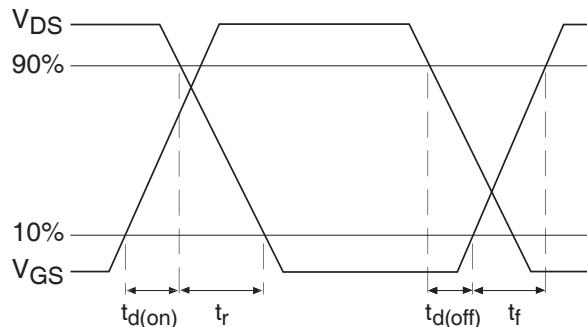


Fig 30b. Switching Time Waveforms

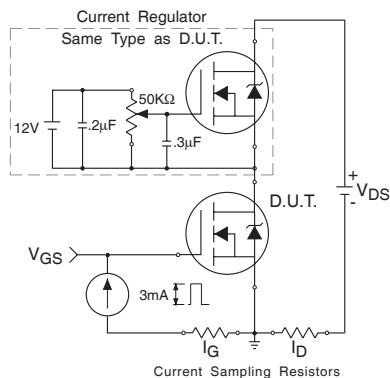


Fig 31a. Gate Charge Test Circuit

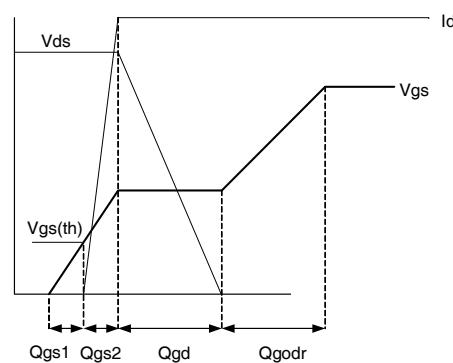
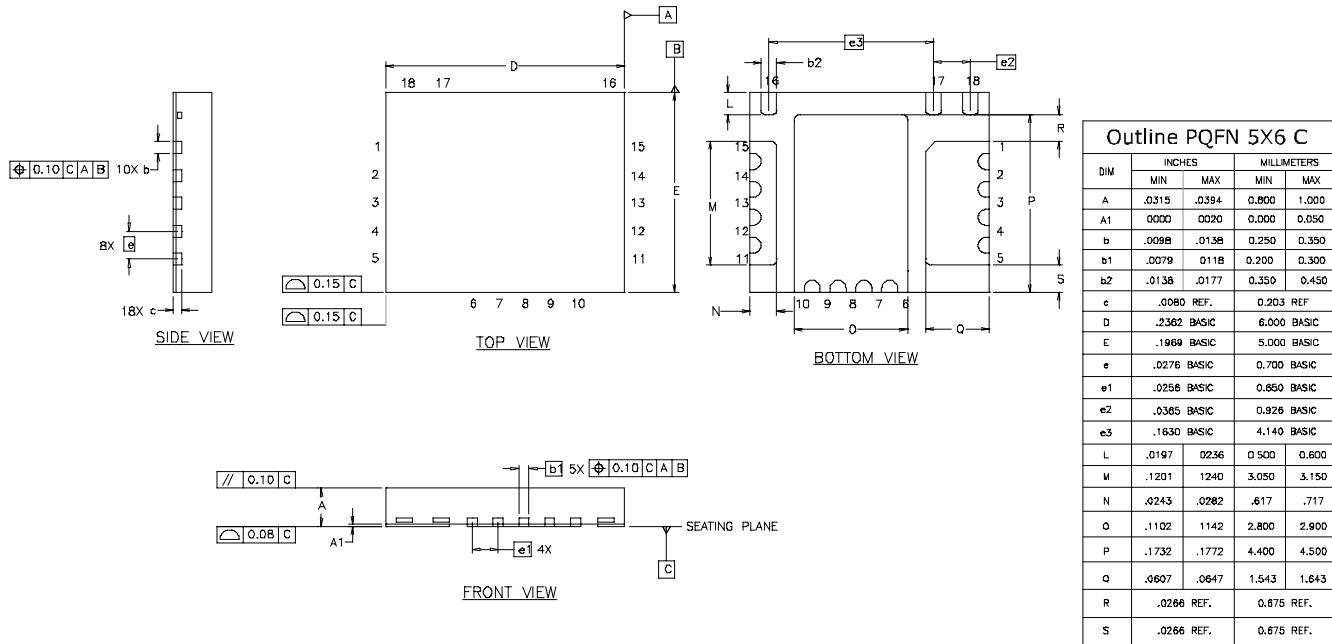


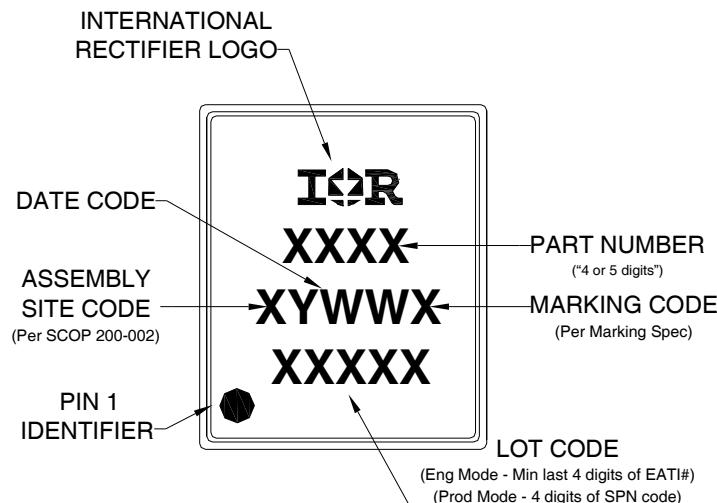
Fig 31b. Gate Charge Waveform

PQFN 5x6 Outline "C" Package Details

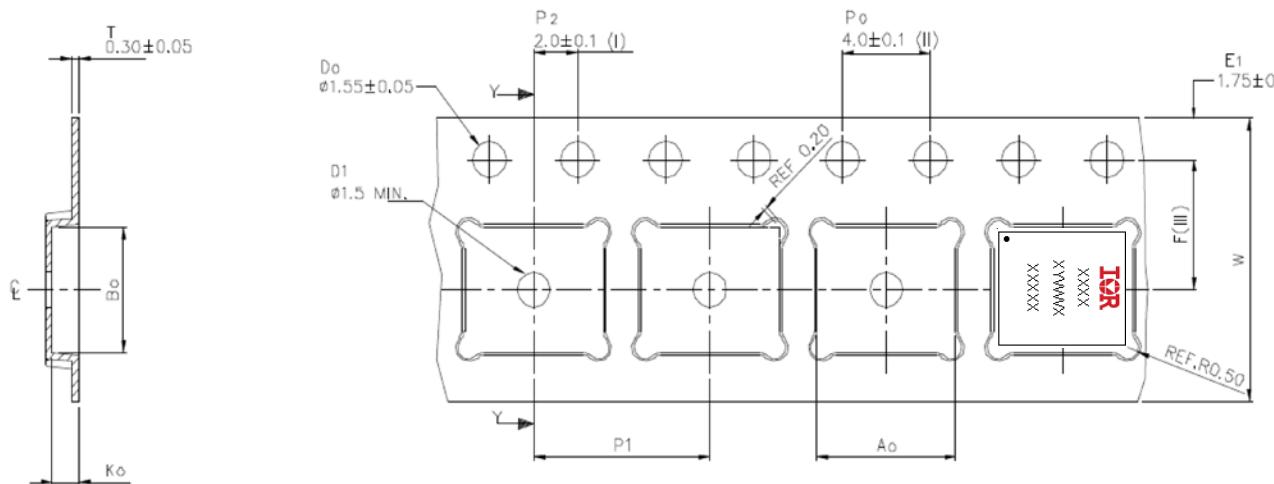


For footprint and stencil design recommendations, please refer to application note AN-1152 at
<http://www.irf.com/technical-info/appnotes/an-1152.pdf>

PQFN 5x6 Outline "C" Part Marking



Note: For the most current drawing please refer to IR website at: <http://www.irf.com/package/>



SECTION Y-Y

A ₀	6.30 +/− 0.1
B ₀	5.30 +/− 0.1
K ₀	1.20 +/− 0.1
F	5.50 +/− 0.1
P ₁	8.00 +/− 0.1
W	12.00 +/− 0.3

(I) Measured from centreline of sprocket hole to centreline of pocket.

(II) Cumulative tolerance of 10 sprocket holes is ± 0.20 .

(III) Measured from centreline of sprocket hole to centreline of pocket.

(IV) Other material available.

(V) Typical SR of form tape Max 10^9 OHM/SQ

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.

Note: For the most current drawing please refer to IR website at: <http://www.irf.com/package/>**Qualification information[†]**

Qualification level	Consumer ^{††} (per JEDEC JESD47F ^{†††} guidelines)	
Moisture Sensitivity Level	PQFN 5mm x 6mm	MSL2 ^{††††} (per JEDEC J-STD-020D ^{†††})
RoHS compliant	Yes	

† Qualification standards can be found at International Rectifier's web site
<http://www.irf.com/product-info/reliability>

†† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information:
<http://www.irf.com/whoto-call/salesrep/>

††† Applicable version of JEDEC standard at the time of product release.

†††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information:
<http://www.irf.com/whoto-call/salesrep/>

Date	Comment
1/8/2010	Pin number on front page drawing has been corrected
7/15/2010	MSL2 Consumer Qualification on page1 has been corrected

Notes:

① Repetitive rating; pulse width limited by max. junction temperature.

Data and specifications subject to change without notice.

② Starting $T_J = 25^\circ\text{C}$,Q1: $L = 0.23\text{mH}$, $R_G = 25\Omega$, $I_{AS} = 10\text{A}$;Q2: $L = 0.15\text{mH}$, $R_G = 25\Omega$, $I_{AS} = 21\text{A}$.③ Pulse width $\leq 400\mu\text{s}$; duty cycle $\leq 2\%$.

④ When mounted on 1 inch square copper board.

⑤ R_g is measured at T_J approximately 90°C .
International
IR Rectifier

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